

Tiny Package, High Efficiency, Step-Up DC/DC Converter

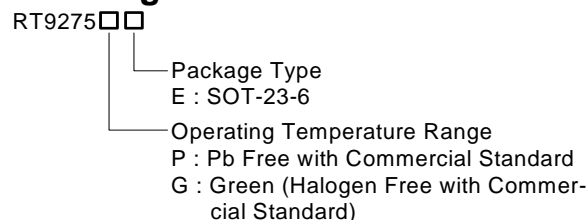
General Description

The RT9275 is a compact, high efficiency, and low voltage step-up DC/DC converter with an Adaptive Current Mode PWM control loop, includes an error amplifier, ramp generator, comparator, switch pass element and driver in which providing a stable and high efficient operation over a wide range of load currents.

The low start-up input voltage below 1V makes RT9275 suitable for 1 to 4 battery cells applications. Both internal 2.5A switch and driver for driving external power devices (NMOS or NPN) are provided. It is incorporating with soft-start function, Under Voltage protection function.

RT9275 is available in SOT-23-6 package.

Ordering Information



Note :

RichTek Pb-free and Green products are :

- ▶RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶Suitable for use in SnPb or Pb-free soldering processes.
- ▶100% matte tin (Sn) plating.

Marking Information

For marking information, contact our sales representative directly or through a RichTek distributor located in your area, otherwise visit our website for detail.

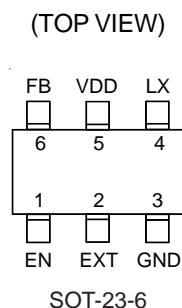
Features

- 1V Low Start-up Input Voltage at 1mA Load
- Zero Shutdown Mode Supply Current
- 90% Efficiency
- 400kHz Switching Frequency
- Providing Flexibility for Using Internal and External Power Switches
- Build Soft-Start function internally
- Under-Voltage Protection
- Small SOT-23-6 Package
- RoHS Compliant and 100% Lead (Pb)-Free

Applications

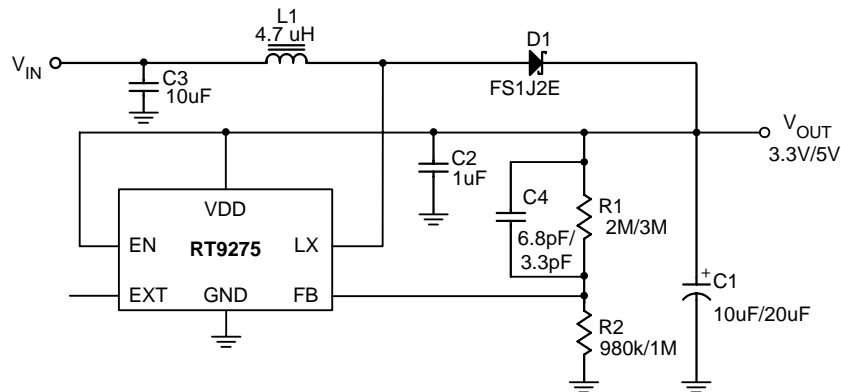
- PDA
- DSC
- LCD Panel
- RF-Tags
- MP3
- Portable Instrument
- Wireless Equipment

Pin Configurations



Note : There is no pin1 indicator on top mark for SOT-23-6 type, and pin 1 will be lower left pin when reading top mark from left to right.

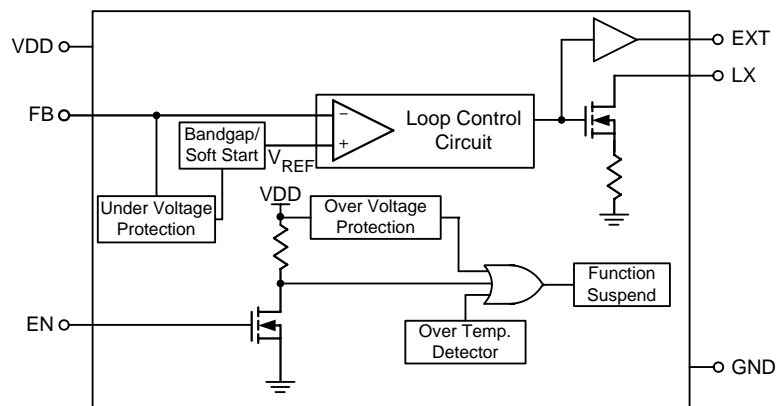
Typical Application Circuit



Functional Pin Description

Pin No.	Pin Name	Pin Function
1	EN	Chip Enable (Active High)
2	EXT	Output pin for driving external NMOS
3	GND	Ground
4	LX	Pin for switching
5	VDD	Input positive power pin of RT9275
6	FB	Feedback input pin. Internal reference voltage for the error amplifier is 1.25V.

Function Block Diagram



Absolute Maximum Ratings (Note 1)

- Supply Voltage ----- 7V
- LX Pin Switch Voltage ----- -0.3V to 7V
- Other I/O Pin Voltages ----- -0.3V to 7V
- LX Pin Switch Current ----- 2.5A
- EXT Pin Driver Current ----- 200mA
- Power Dissipation, P_D @ T_A = 25°C
 SOT-23-6 ----- 0.4W
- Package Thermal Resistance (Note 3)
 SOT-23-6, θ_{JA} ----- 250°C/W
- Junction Temperature ----- 150°C
- Lead Temperature (Soldering, 10 sec.) ----- 260°C
- Storage Temperature Range ----- -65°C to +150°C
- ESD Susceptibility (Note 2)
 HBM (Human Body Mode) ----- 2kV
 MM (Machine Mode) ----- 200V

Electrical Characteristics

(V_{IN} = 1.5V, V_{OUT} = V_{DD} = 3.3V, T_A = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Start-UP Voltage	V _{ST}	I _L = 1mA	--	0.9	1.0	V
Operating V _{DD} Range	V _{DD}	V _{DD} pin voltage	2	--	6	V
No Load Current I (V _{IN}) (Note 4)	I _{NO LOAD}	V _{IN} = 1.5V, V _{OUT} = 3.3V	--	160	200	μA
Continuous Switching Current	I _{SWITCH}	V _{IN} = EN = 3.3V, V _{FB} = GND	0.2	0.3	0.5	mA
Switch-off Current I (V _{DD})	I _{SWITCH OFF}	V _{IN} = 6V	--	50	75	μA
Shutdown Current I (V _{IN})	I _{OFF}	EN = 0V, V _{IN} = 4.5V	--	0.01	1	μA
Feedback Reference Voltage	V _{REF}	Close Loop, V _{DD} = 3.3V	1.225	1.25	1.275	V
Output Voltage Temperature Coefficient (refer to V _{FB})	T _s	T _A = -40°C to 85°C	--	50	--	ppm/°C
Switching Frequency	F _S	V _{DD} = 3.3V	300	400	500	kHz
Frequency Temperature Coefficient	Δf	T _A = -40°C to 85°C		0.3		%/°C
Maximum Duty	D _{MAX}	V _{DD} = 3.3V	85	90	--	%
LX ON Resistance		V _{DD} = 3.3V	--	0.3	1.1	Ω
Current Limit Setting (Note 5)	I _{LIM}	V _{DD} = 3.3V	1.5	2.0	2.5	A
EXT ON Resistance to V _{DD}		V _{DD} = 3.3V	--	5	8.5	Ω
EXT ON Resistance to GND		V _{DD} = 3.3V	--	5	8.5	Ω
Line Regulation (refer to V _{FB})	ΔV _{LINE}	V _{DD} = 3.5 ~ 6V, I _L = 1mA	--	1.5	10	mV/V
Load Regulation (Note 6)	ΔV _{LOAD}	V _{IN} = 2.5V, I _L = 1 ~ 100mA	--	0.25	--	mV/mA
V _{DD} Over Voltage Protection			6.3	6.8	7.3	V
EN Pin Trip Level		V _{DD} = 3.3V	0.4	0.8	1.2	V

To be continued

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Soft Start time	T_{SS}		3.0	6.0	12	ms
Under Voltage Protection – Threshold Voltage	V_{TH-UVP}		0.75	0.85	0.95	V
Thermal Shutdown	T_{SD}		--	165	--	°C
Thermal Shutdown Hysterises	ΔT_{SD}		--	10	--	°C

Note 1. Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.

Note 2. Devices are ESD sensitive. Handling precaution recommended.

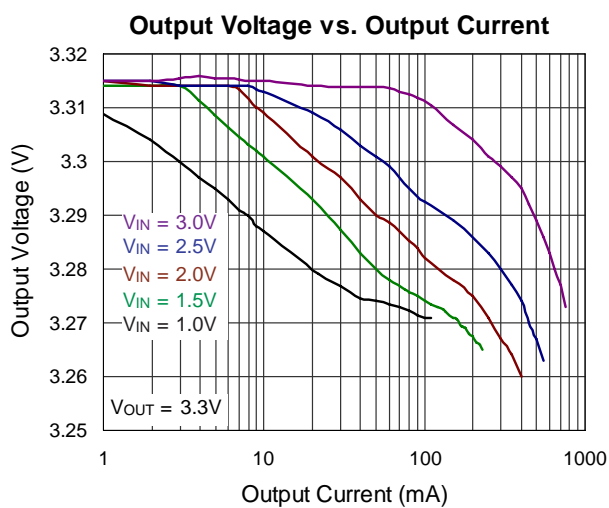
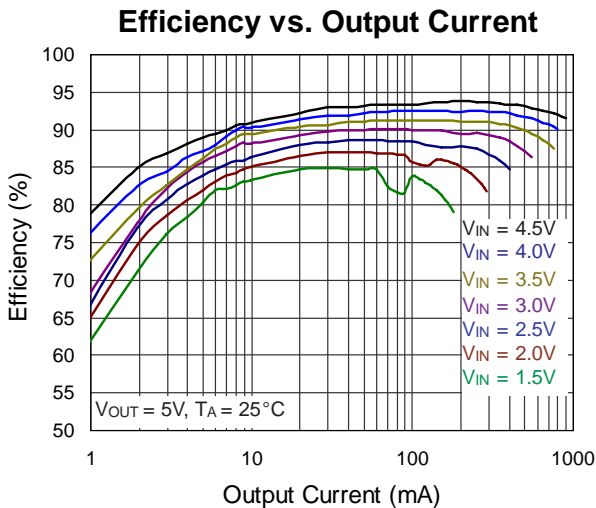
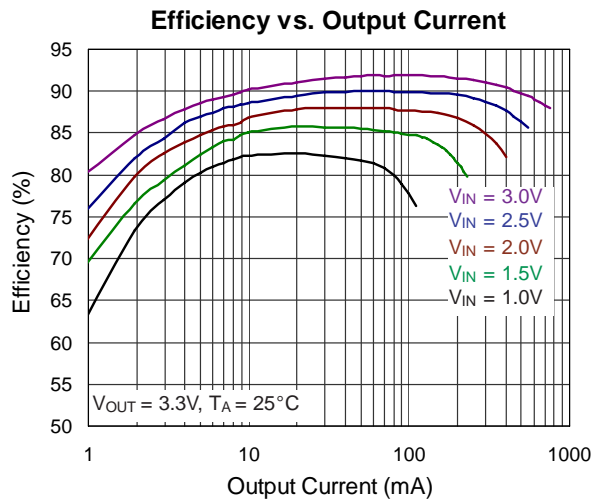
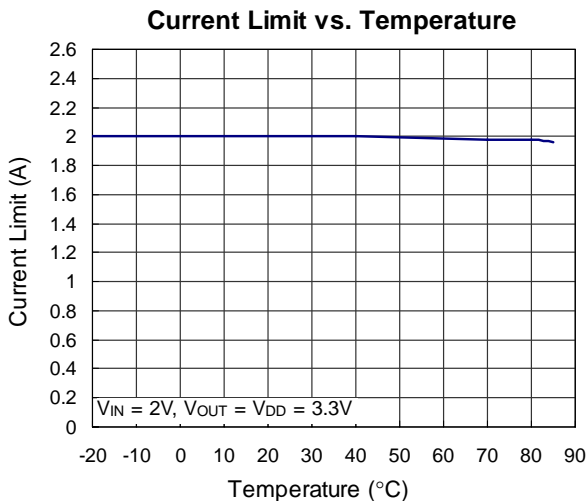
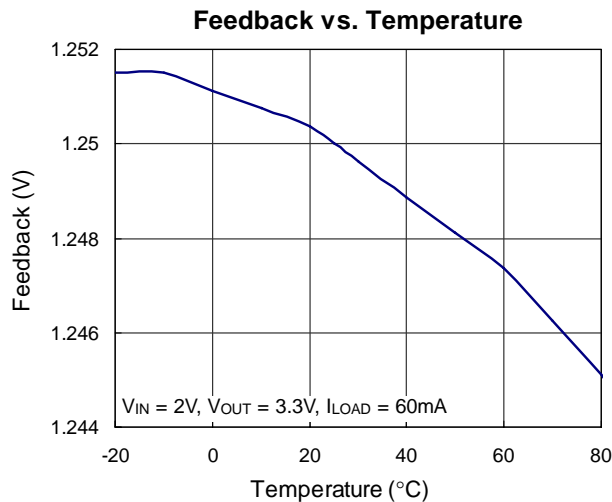
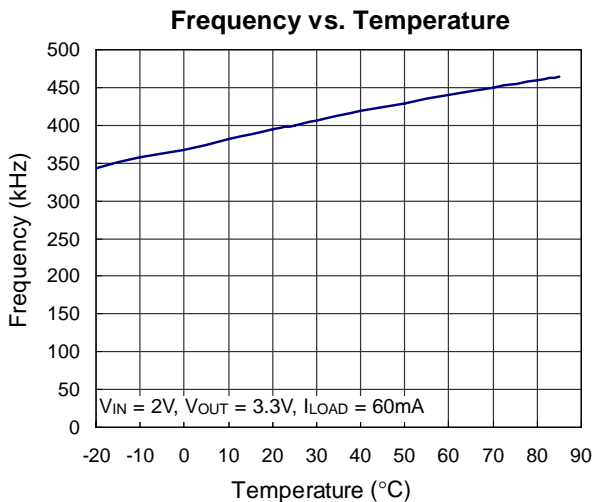
Note 3. θ_{JA} is measured in the natural convection at $T_A = 25^\circ\text{C}$ on a low effective thermal conductivity test board of JEDEC 51-3 thermal measurement standard.

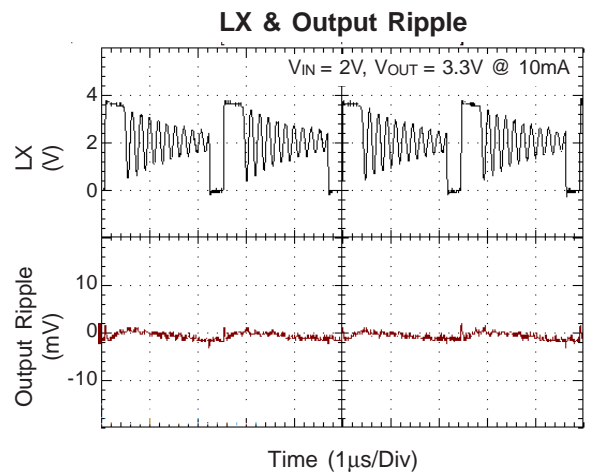
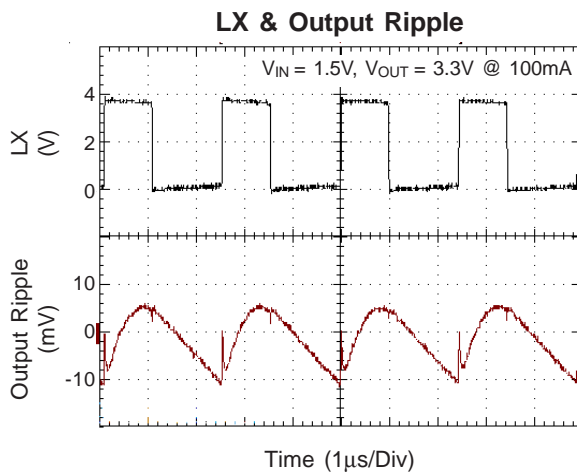
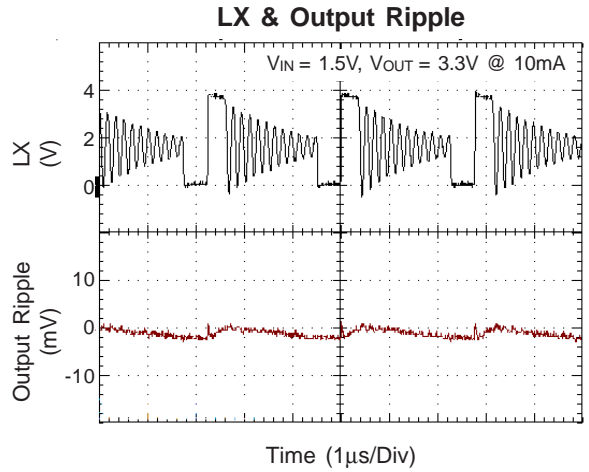
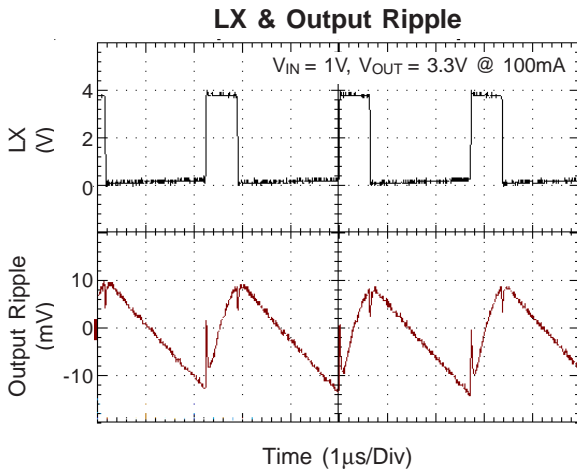
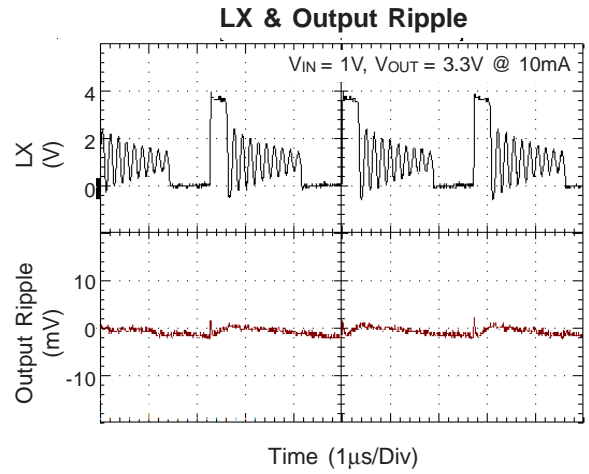
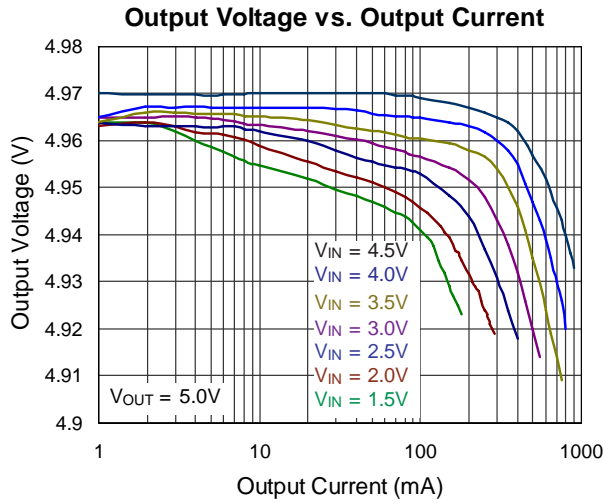
Note 4. No Load Current is highly dependent on practical system design and component selection that cannot be covered by production testing. Typical No Load Current is verified by typical application circuit with recommended components. No Load Current performance is guaranteed by Switch Off Current and Continuous Switching Current.

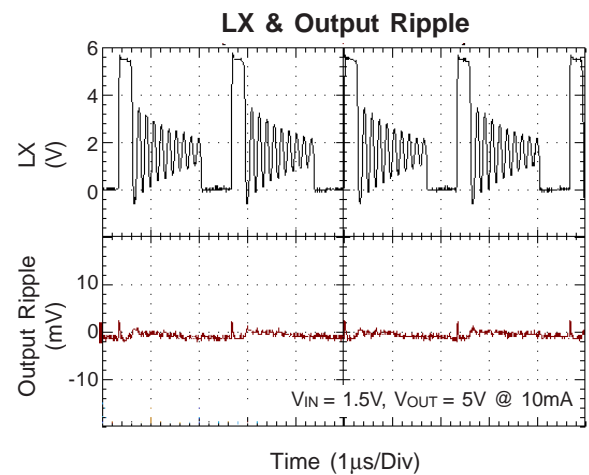
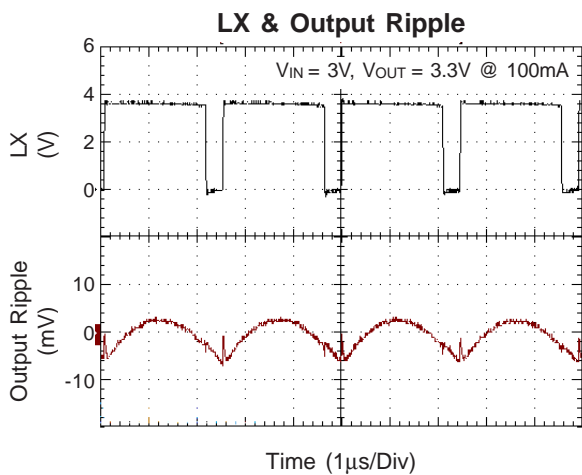
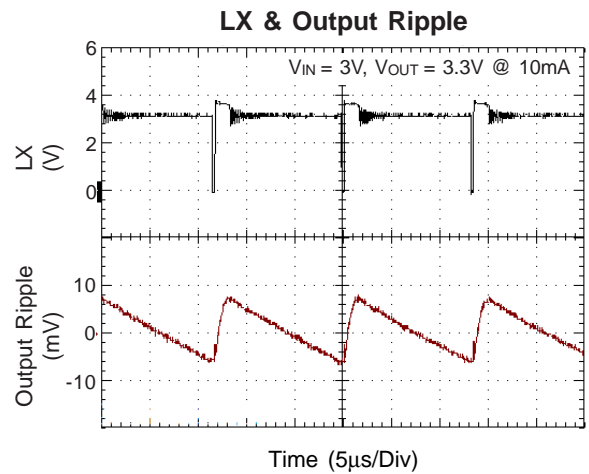
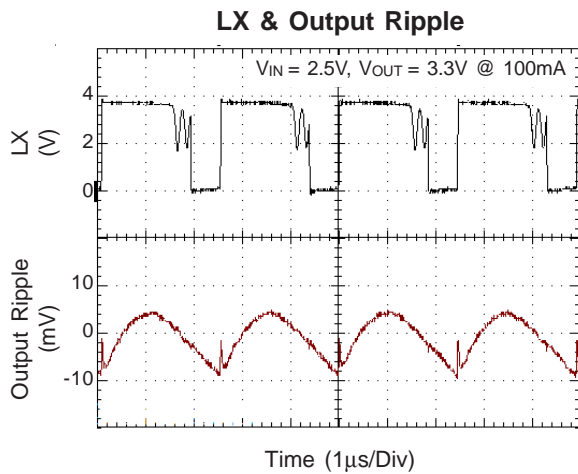
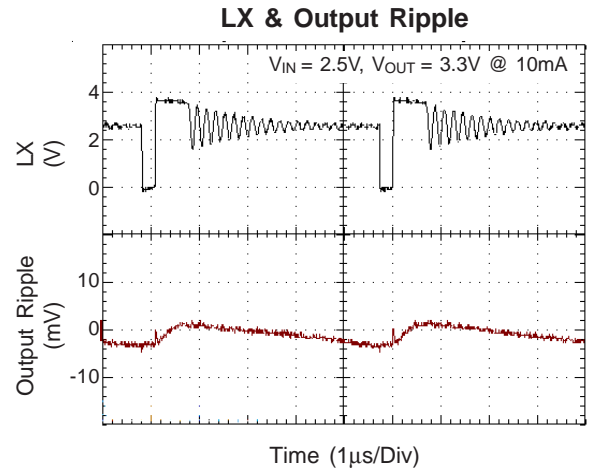
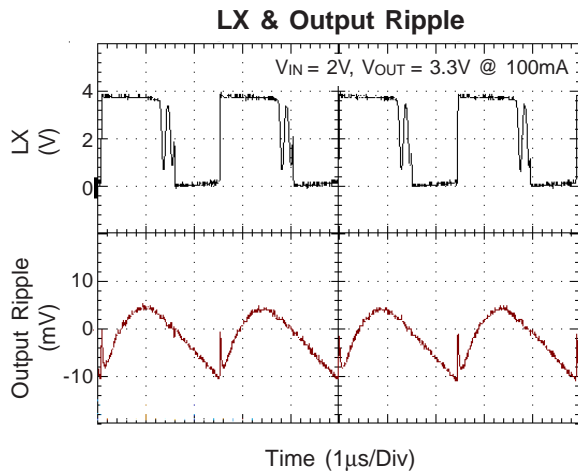
Note 5. Current Limit is guaranteed by design at $T_A = 25^\circ\text{C}$.

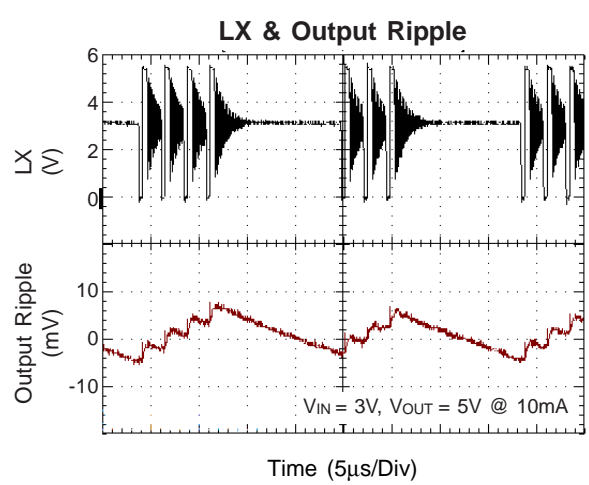
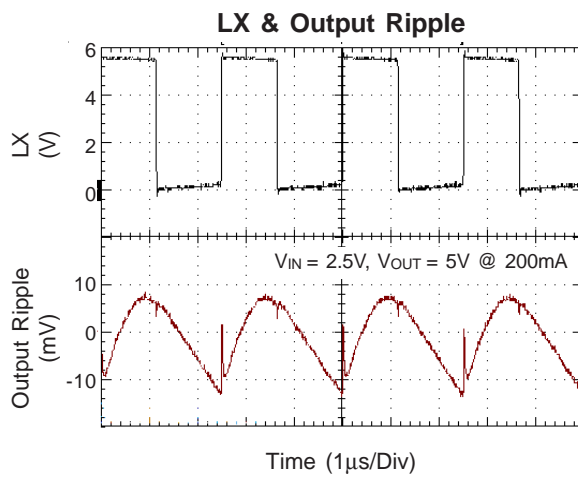
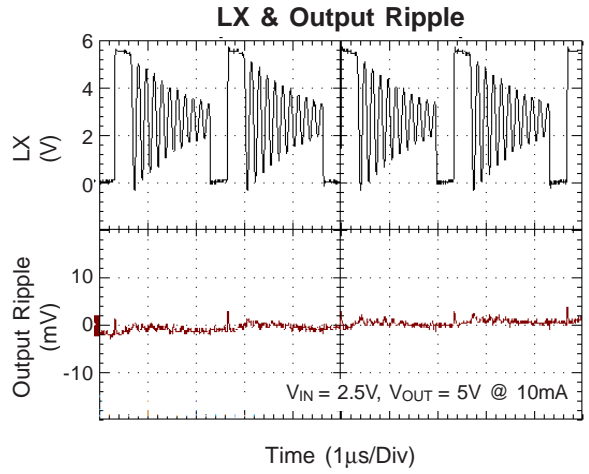
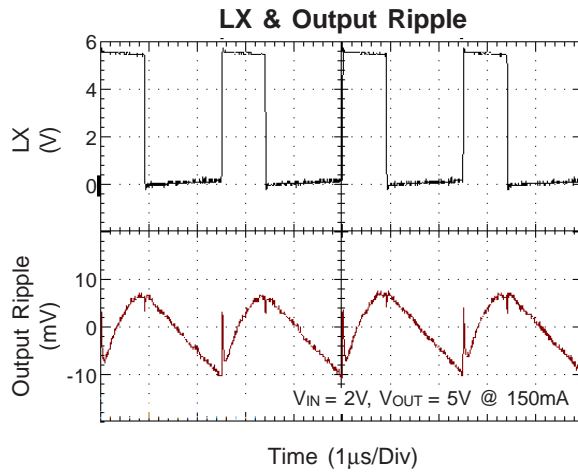
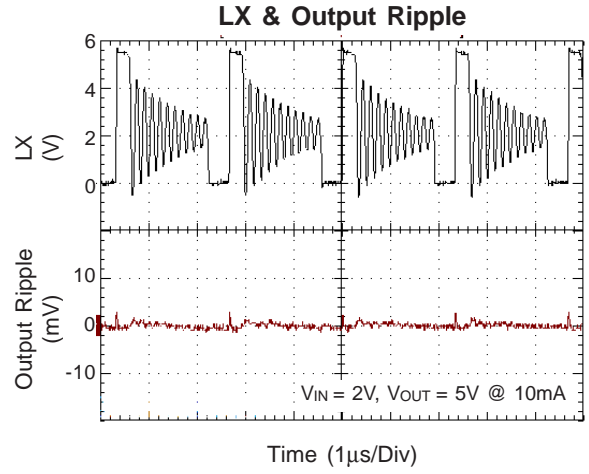
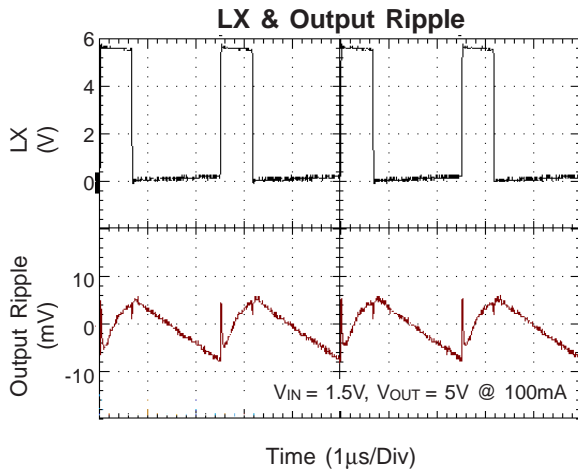
Note 6. Load Regulation is not tested at production due to practical instrument limitation. Load Regulation performance is dominantly dependent on DC loop gain and LX ON Resistance that are guaranteed by "Line Regulation" and "LX ON Resistance" tests in production.

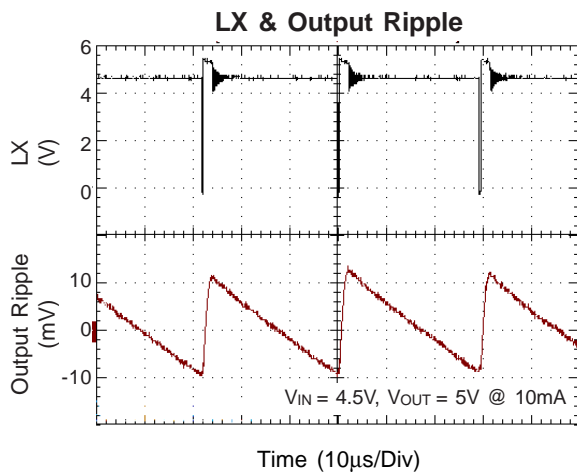
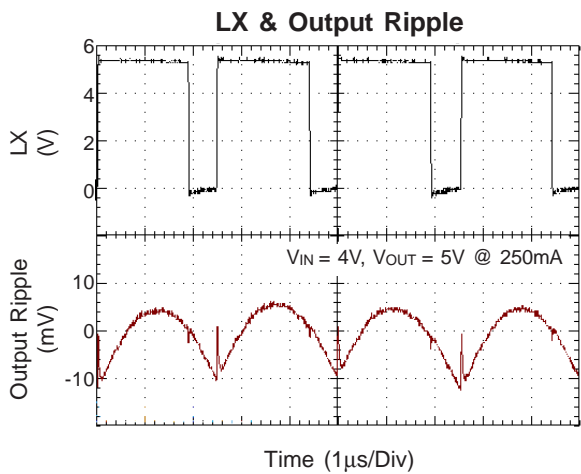
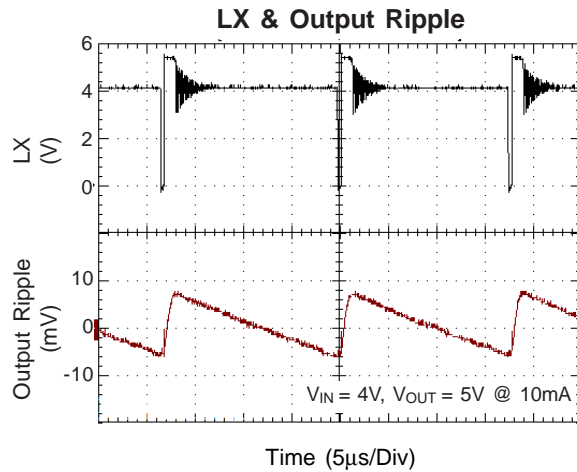
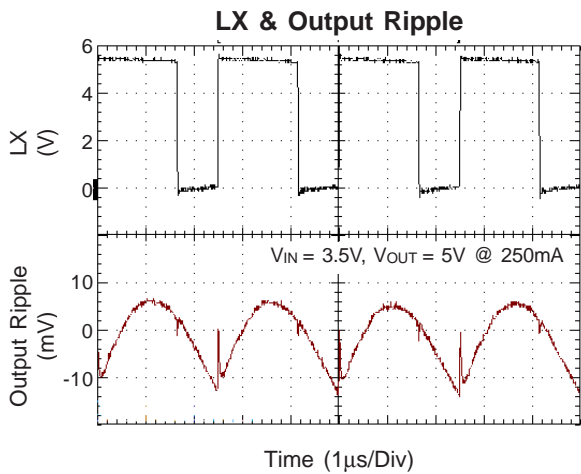
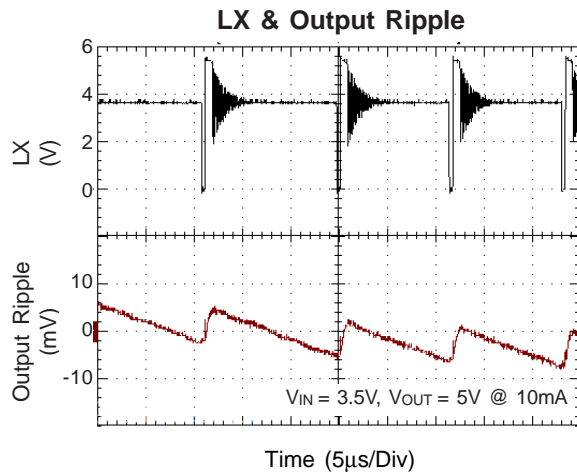
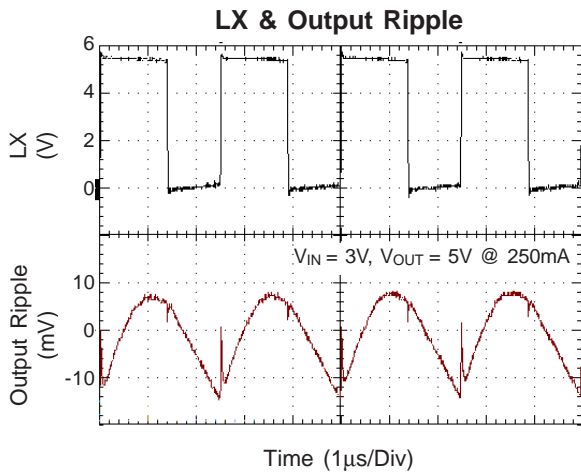
Typical Operating Characteristics

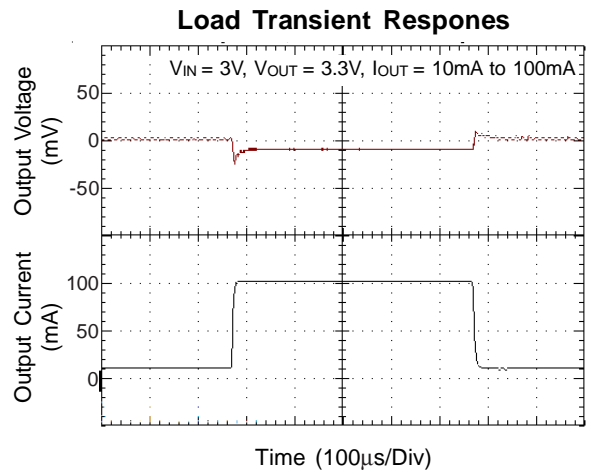
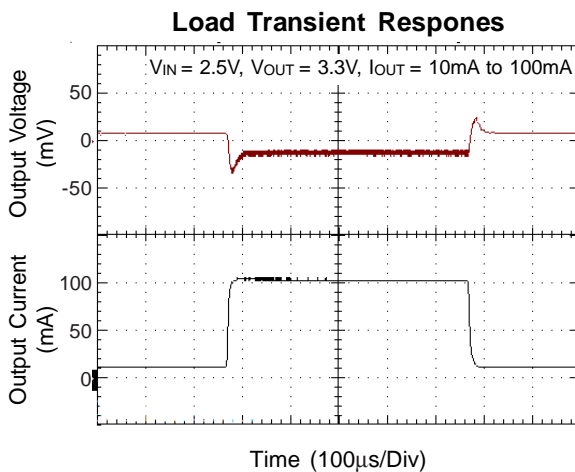
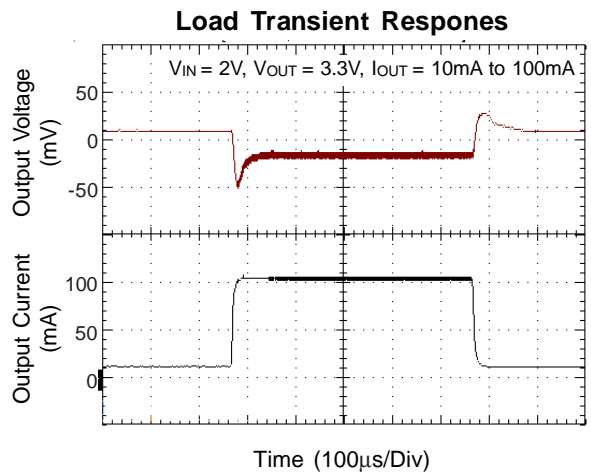
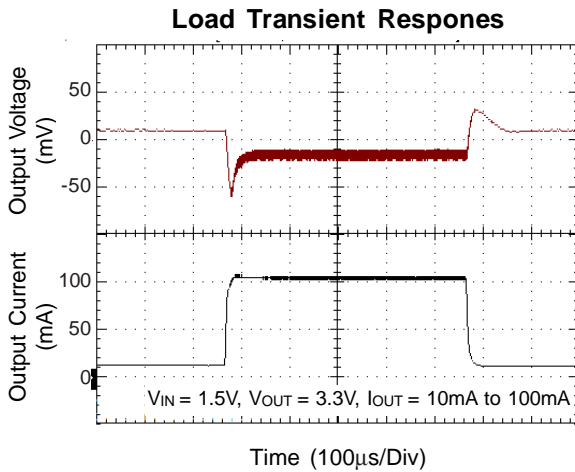
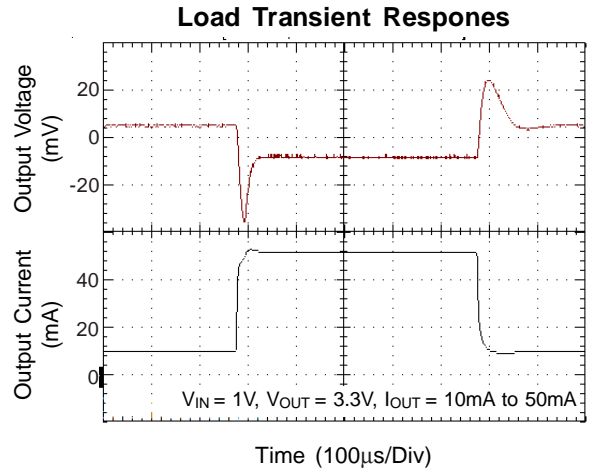
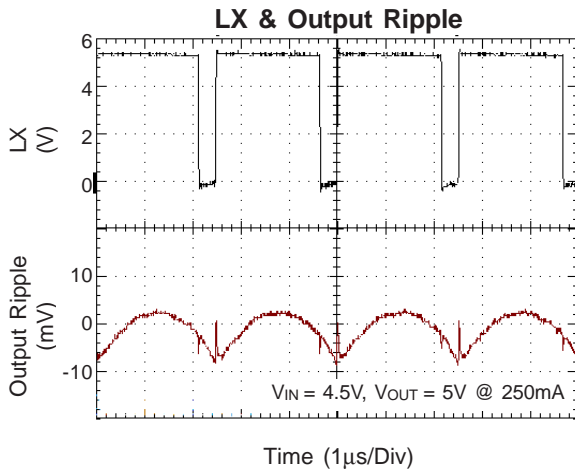




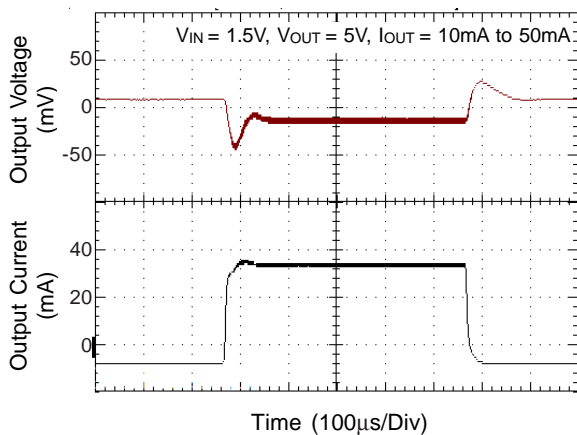




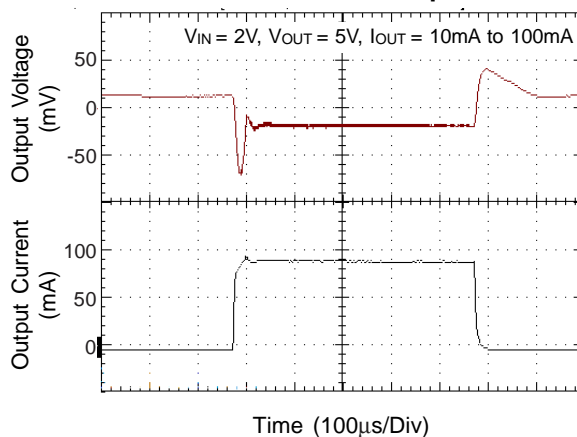




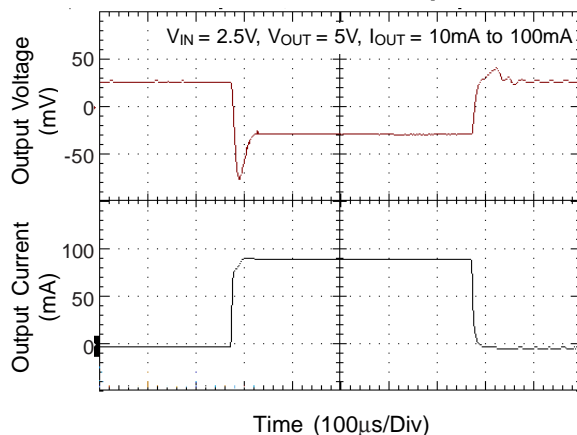
Load Transient Responses



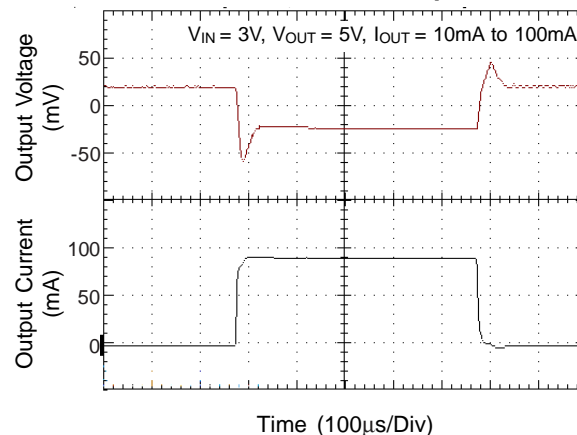
Load Transient Responses



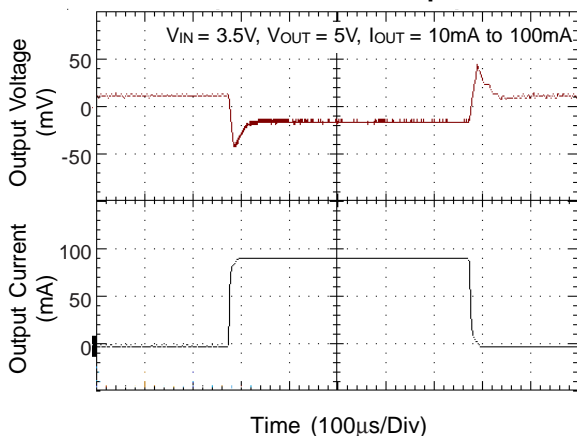
Load Transient Responses



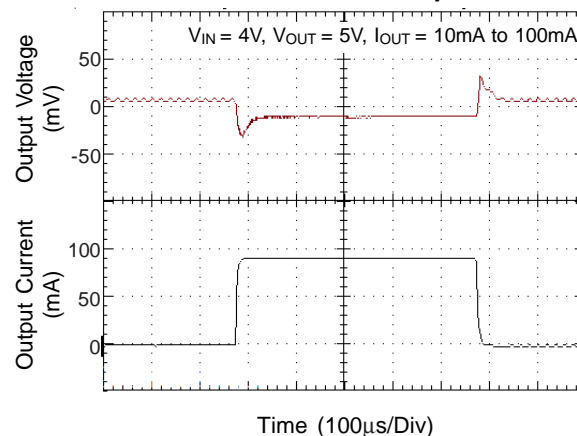
Load Transient Responses

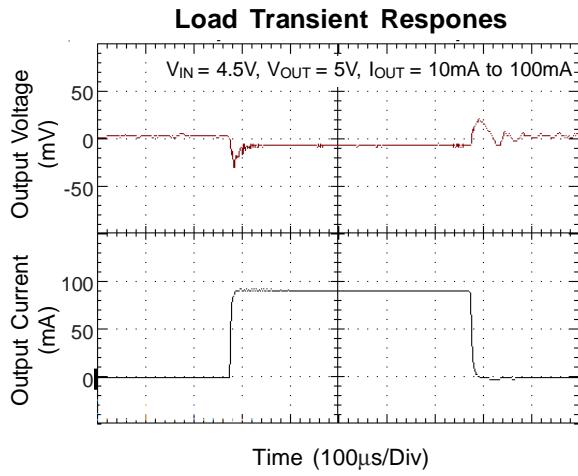


Load Transient Responses



Load Transient Responses





Application Information

Output Voltage Setting

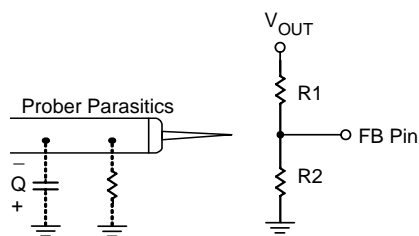
Referring to Typical Application Circuits, the output voltage of the switching regulator (V_{OUT}) can be set with Equation (1).

$$V_{OUT} = \left(1 + \frac{R1}{R2}\right) \times 1.25V \quad (1)$$

Feedback Loop Design

Referring to Typical Application Circuits. The selection of R1 and R2 based on the trade-off between quiescent current consumption and interference immunity is stated below:

- Follow Equation (1)
- Higher R reduces the quiescent current (Path current = $1.25V/R2$), however resistors beyond $5M\Omega$ are not recommended.
- Lower R gives better noise immunity, and is less sensitive to interference, layout parasitics, FB node leakage, and improper probing to FB pins.



- A proper value of feed forward capacitor parallel with R1 can improve the noise immunity of the feedback loops, especially in an improper layout. An empirical suggestion is

$$\frac{1}{2\pi R1C4} = 10 \text{ to } 20\text{kHz}$$

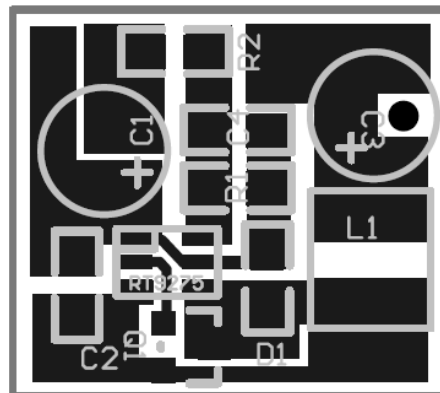
For applications without standby or suspend modes, lower values of R1 and R2 are preferred. For applications concerning the current consumption in standby or suspend modes, the higher values of R1 and R2 are needed. Such “high impedance feedback loops” are sensitive to any interference, which require careful layout and avoid any interference, e.g. probing to FB pin.

Layout Guide

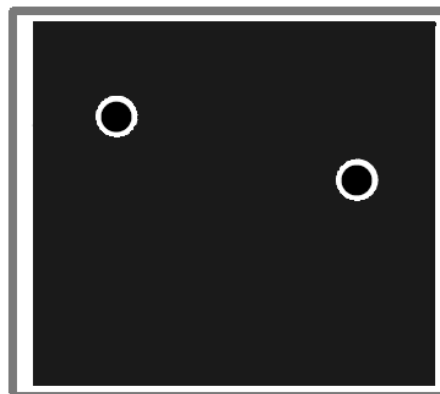
- A full GND plane without gap break.
- V_{DD} to GND noise bypass – Short and wide connection for the $1\mu F$ MLCC capacitor between Pin5 and Pin3.
- V_{IN} to GND noise bypass – Add a capacitor close to L1 inductor, when V_{IN} is not an idea voltage source.
- Minimized FB node copper area and keep far away from noise sources.
- Minimized parasitic capacitance connecting to LX and EXT nodes, which may cause additional switching loss.

Board Layout Example (2-Layer Board)

(Refer to Typical Application Circuit for the board)

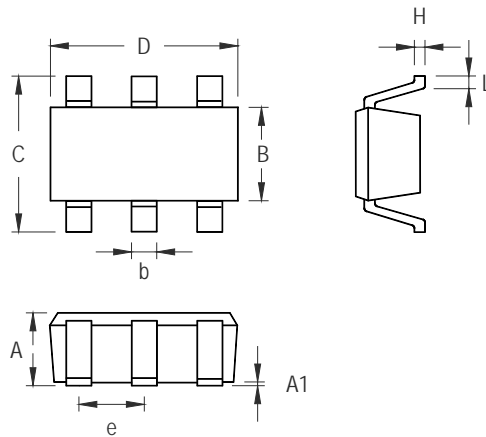


- Top Layer -



- Bottom Layer -

Outline Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.889	1.295	0.031	0.051
A1	0.000	0.152	0.000	0.006
B	1.397	1.803	0.055	0.071
b	0.250	0.560	0.010	0.022
C	2.591	2.997	0.102	0.118
D	2.692	3.009	0.106	0.122
e	0.838	1.041	0.033	0.041
H	0.080	0.254	0.003	0.010
L	0.300	0.610	0.012	0.024

SOT-23-6 Surface Mount Package

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